





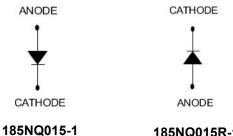
## 185NQ015/R-1 SCHOTTKY RECTIFIER



### **Features**

- 125℃ T<sub>J</sub> operation
- Unique high power, Half-Pak module
- Replaces three parallel DO-5'S
- Easier to mount and lower profile than DO-5' S
- High purity, high temperature epoxy encapsulation for enhanced
- mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Baseplate: Nickel plated; Terminals: Nickel plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



#### 185NQ015R-1

### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- **Reverse battery protection**

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	15	V
Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> =66°C, rectangular wave form	180	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	2700	Α
Non-Repetitive Avalanche Energy	E <sub>AS</sub>	T <sub>J</sub> =25 °C ,I <sub>AS</sub> =2A,L=4.5mH	9	mJ
Repetitive Avalanche Current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ sec Frequency limited by $T_J$ max. $V_A$ =3 $\times$ $V_R$ typical	2	Α

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## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	\/	@ 180A, Pulse, T <sub>J</sub> = 25 °C	0.35	0.40	V
	$V_{F1}$	@ 360A, Pulse, T <sub>J</sub> = 25 °C	-	0.51	V
	\/	@ 180A, Pulse, T <sub>J</sub> = 75 °C	0.30	0.34	V
	$V_{F2}$	@ 360A, Pulse, T <sub>J</sub> = 75 °C	-	0.45	V
Reverse Current*	I <sub>R1</sub>	$@V_R = \text{rated } V_R T_J = 25 ^{\circ}\text{C}$	15	60	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 100 °C	1500	3000	mA
	I <sub>R3</sub>	@V <sub>R</sub> = 12V, T <sub>J</sub> = 100 °C	1100	2670	mA
	$I_{R4}$	@V <sub>R</sub> = 5V, T <sub>J</sub> = 100 °C	700	1620	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	10000	12300	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

 $<sup>^*</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2%

## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification		Units
Junction Temperature	Τ <sub>J</sub>	-	-55 to +125		°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +125		°C
Typical Thermal Resistance Junction to Case	R <sub>0</sub> JC	DC operation	0.30		°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.15		°C/W
Mounting Torque	Тм	Non-lubricated threads	Mounting Torque Terminal	23(min) 29(max) 35(min)	- Kg-cm
			Torque	46(max)	
Approximate Weight	wt	-	25.6		g
Case Style	PRM1-1				

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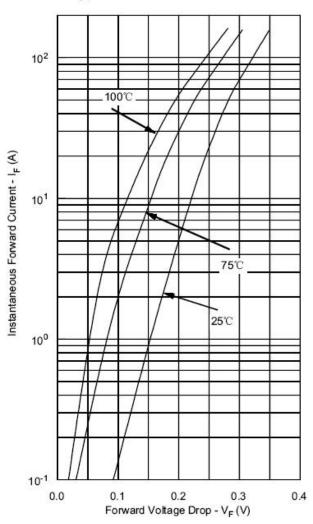




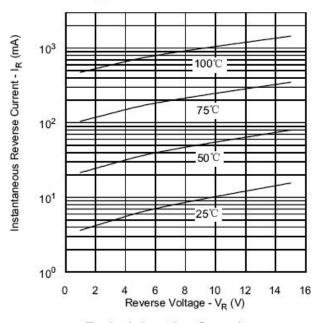


### **Ratings and Characteristics Curves**

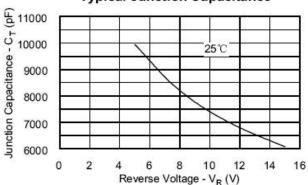
### **Typical Forward Characteristics**



### Typical Reverse Characteristics



### **Typical Junction Capacitance**

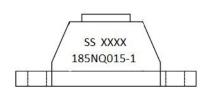


## **Ordering Information**

Device	Package	Shipping		
185NQ015-1	PRM1-1(Pb-Free)	27pcs/ box		

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# **Marking Diagram**



Where XXXX is YYWW

1st row SS YYWW
2nd row 185NQ015-1
SS = SS
YY = Year
WW = Week

Cautions: Molding resin

Epoxy resin UL:94V-0

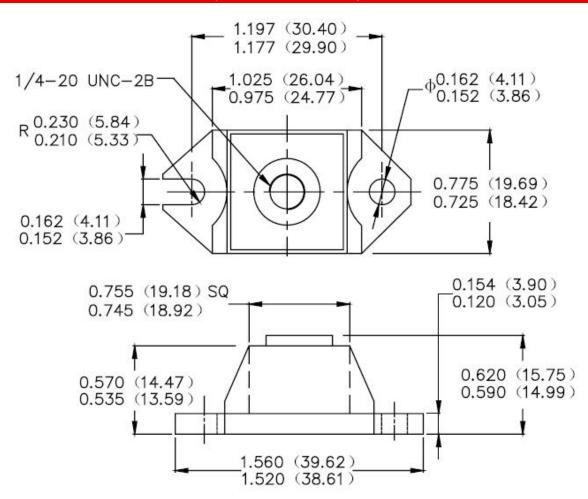
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## **Mechanical Dimensions PRM1-1 (Inches/Millimeters)**



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